

RoHS

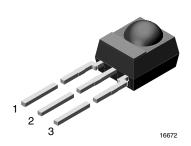
GREEN (5-2008)



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IR Receiver Modules for Remote Control Systems



MECHNICAL DATA

Pinning for HS0038BD:

 $1 = OUT, 2 = GND, 3 = V_S$

FEATURES

- Very low supply current
- · Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- · Improved shielding against EMI
- Supply voltage: 2.5 V to 5.5 V
- · Improved immunity against ambient light
- Insensitive to supply voltage ripple and noise
- Material categorization: For definitions of compliance

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

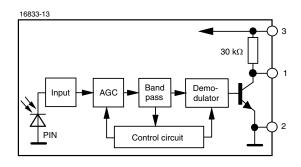
These products are miniaturized receivers for infrared remote control systems. A PIN diode and a preamplifier are assembled on a lead frame, the epoxy package acts as an IR filter.

The demodulated output signal can be directly decoded by a microprocessor. The HS0038BD is compatible with all common IR remote control data formats and can suppress almost all spurious pulses from energy saving fluorescent lamps.

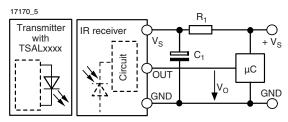
This component has not been qualified according to automotive specifications.

PARTS TABLE			
CARRIER FREQUENCY	STANDARD APPLICATIONS (AGC2)		
38 kHz	HS0038BD		

BLOCK DIAGRAM



APPLICATION CIRCUIT



 $R_{_1}$ and $C_{_1}$ are recommended for protection against EOS. Components should be in the range of 33 Ω < $R_{_1}$ < 1 $k\Omega,$ $C_{_1}$ > 0.1 $\mu F.$



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Supply voltage		Vs	- 0.3 to + 6	V			
Supply current		I _S	3	mA			
Output voltage		Vo	- 0.3 to (V _S + 0.3)	V			
Output current		Io	5	mA			
Junction temperature		T _j	100	°C			
Storage temperature range		T _{stg}	- 25 to + 85	°C			
Operating temperature range		T _{amb}	- 25 to + 85	°C			
Power consumption	T _{amb} ≤ 85 °C	P _{tot}	10	mW			
Soldering temperature	$t \le 10 \text{ s}, 1 \text{ mm from case}$	T _{sd}	260	°C			

Note

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only
and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification
is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

ELECTRICAL AND OPTICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply current	$E_{v} = 0, V_{S} = 3.3 V$	I _{SD}	0.27	0.35	0.45	mA
	$E_v = 40 \text{ klx, sunlight}$	I _{SH}		0.45		mA
Supply voltage		V _S	2.5		5.5	V
Transmission distance	E_{v} = 0, test signal see fig. 1, IR diode TSAL6200, I_{F} = 150 mA	d		45		m
Output voltage low	$I_{OSL} = 0.5 \text{ mA}, E_e = 0.7 \text{ mW/m}^2,$ test signal see fig. 1	V _{OSL}			100	mV
Minimum irradiance	Pulse width tolerance: t_{pi} - 5/f ₀ < t_{po} < t_{pi} + 6/f ₀ , test signal see fig. 1	E _{e min.}		0.08	0.15	mW/m²
Maximum irradiance	t_{pi} - 5/f ₀ < t_{po} < t_{pi} + 6/f ₀ , test signal see fig. 1	E _{e max.}	30			W/m²
Directivity	Angle of half transmission distance	Ψ1/2		± 45		deg

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

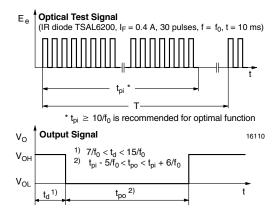


Fig. 1 - Output Active Low

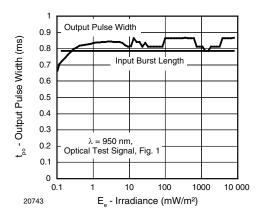


Fig. 2 - Pulse Length and Sensitivity in Dark Ambient



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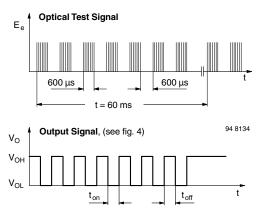


Fig. 3 - Output Function

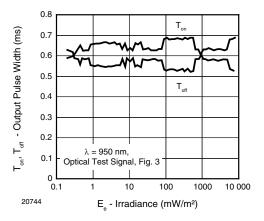


Fig. 4 - Output Pulse Diagram

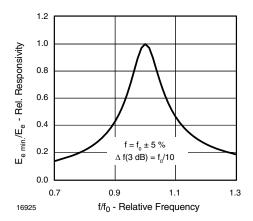


Fig. 5 - Frequency Dependence of Responsivity

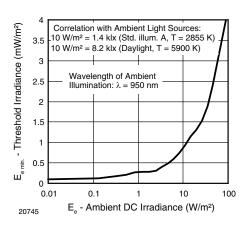


Fig. 6 - Sensitivity in Bright Ambient

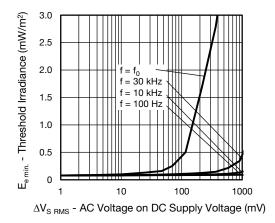


Fig. 7 - Sensitivity vs. Supply Voltage Disturbances

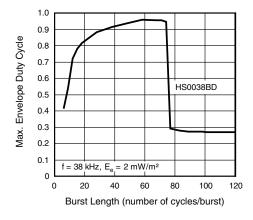


Fig. 8 - Max. Envelope Duty Cycle vs. Burst Length



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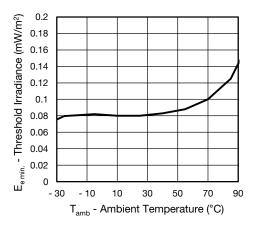


Fig. 9 - Sensitivity vs. Ambient Temperature

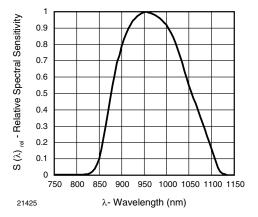


Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

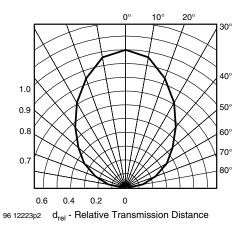


Fig. 11 - Horizontal Directivity

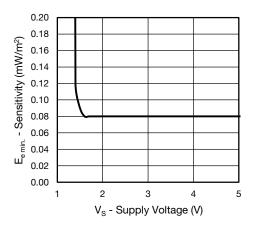


Fig. 12 - Sensitivity vs. Supply Voltage



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SUITABLE DATA FORMAT

These products are designed to suppress spurious output pulses due to noise or disturbance signals. Data and disturbance signals can be distinguished by the devices according to carrier frequency, burst length and envelope duty cycle. The data signal should be close to the band-pass center frequency (e.g. 38 kHz) and fulfill the conditions in the table below.

When a data signal is applied to the IR receiver in the presence of a disturbance signal, the sensitivity of the receiver is reduced to insure that no spurious pulses are present at the output. Some examples of disturbance signals which are suppressed are:

- DC light (e.g. from tungsten bulb or sunlight)
- · Continuous signals at any frequency
- Strongly or weakly modulated noise from fluorescent lamps with electronic ballasts (see figure 14 or figure 15)

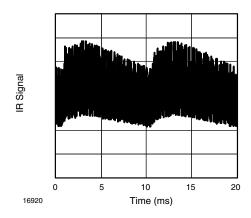


Fig. 13 - IR Signal from Fluorescent Lamp with Low Modulation

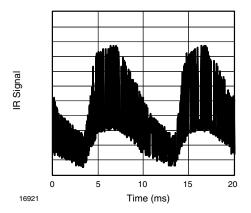


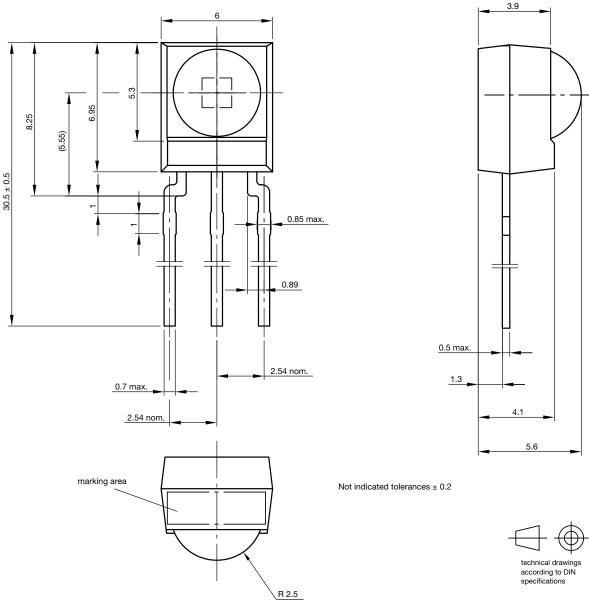
Fig. 14 - IR Signal from Fluorescent Lamp with High Modulation

	HS0038BD			
Minimum burst length	10 cycles/burst			
After each burst of length a minimum gap time is required of	10 to 70 cycles ≥ 10 cycles			
For bursts greater than a minimum gap time in the data stream is needed of	70 cycles > 4 x burst length			
Maximum number of continuous short bursts/second	1800			
Recommended for NEC code	yes			
Recommended for RC5/RC6 code	yes			
Recommended for Sony code	yes			
Recommended for Thomson 56 kHz code	yes			
Recommended for Mitsubishi code (38 kHz, preburst 8 ms, 16 bit)	yes			
Recommended for Sharp code	yes			
Suppression of interference from fluorescent lamps	Most common disturbance signals are suppressed			



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PACKAGE DIMENSIONS in millimeters



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